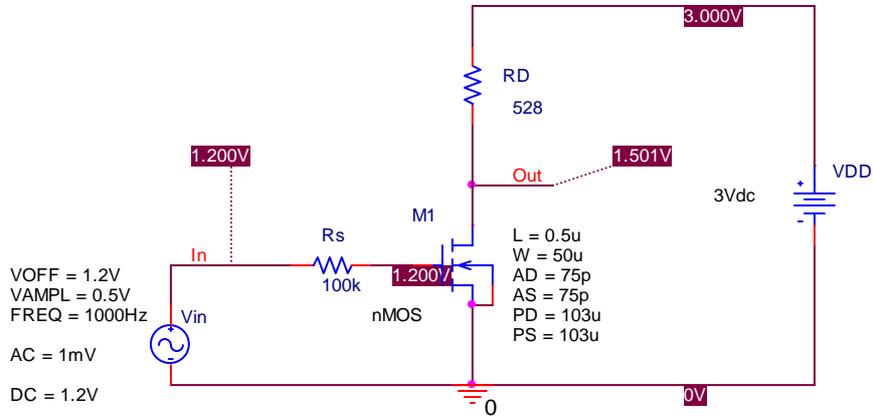


CS frequency response, small example

2010-02-02 /Bengt M.

CS gain stage with output resistance 100k from source generator



Changing table 2.1 MOS model, adding overlap capacitance CGS

```
.model nMOS NMOS
+ LEVEL=1      VTO=0.7      GAMMA=0.45    PHI=0.9
+ NSUB=9E+14   LD=0.08E-6   UO=350       LAMBDA=0.1
+ TOX=9E-9     PB=0.9       CJ=0.56E-3   CJSW=0.35E-11
+ MJ=0.45      MJSW=0.2    CGDO=0.4E-9  JS=1.0E-8
+ CGSO=0.4E-9
```

NAME	M_M1
MODEL	nMOS
ID	2.84E-03
VGS	1.20E+00
VDS	1.50E+00
VBS	0.00E+00
VTH	7.00E-01
VDSAT	5.00E-01
GM	1.14E-02
GDS	2.47E-04
GMB	2.69E-03
CBD	2.73E-14
CBS	4.24E-14
CGSOV	2.00E-14
CGDOV	2.00E-14
CGBOV	0.00E+00
CGS	4.35E-14
CGD	0.00E+00
CGB	0.00E+00

Capacitances from simulation

$$C_{GS} = C_{GSOV} + C_{GS} = 2 \cdot 10^{-14} + 4.35 \cdot 10^{-14} = 6.35 \cdot 10^{-14} \text{ F}$$

$$C_{GD} = C_{GDOV} = 2 \cdot 10^{-14} \text{ F}$$

$$C_{GB} = 0$$

$$C_{DB} = 2.73 \cdot 10^{-14} \text{ F}$$

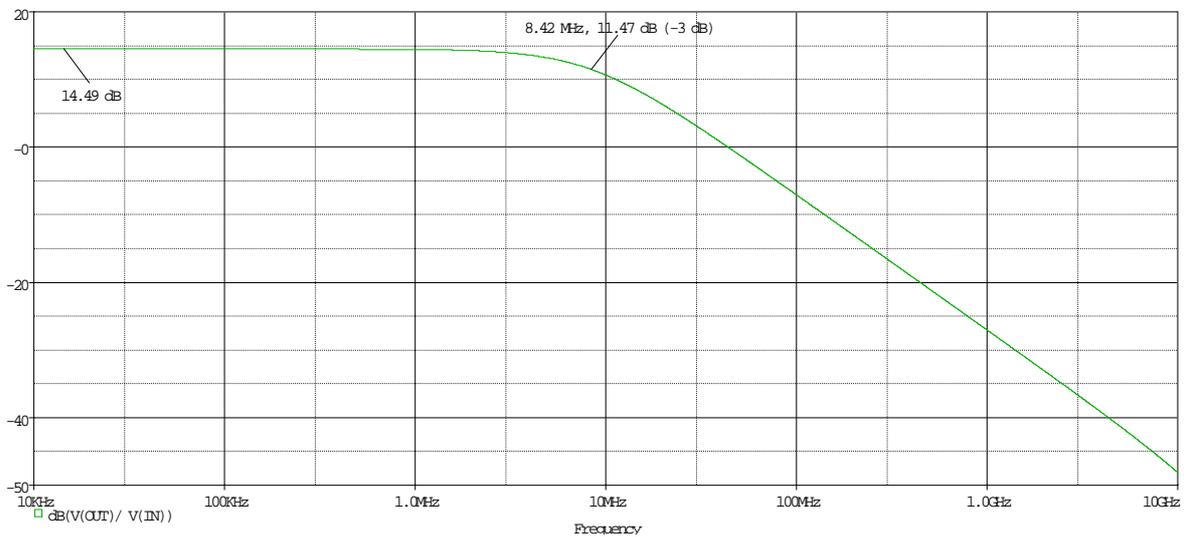
$$r_o = \frac{1}{G_{DS}} = 4049 \Omega$$

Input pole

$$f_{p,in} = \frac{1}{2\pi R_s (C_{GS} + (1 + g_m(R_D // r_o)) C_{GD})} =$$
$$= \frac{1}{2\pi \cdot 100 \cdot 10^3 (6,35 \cdot 10^{-14} + (1 + 1,14 \cdot 10^{-2} \cdot 528 // 4049) 2 \cdot 10^{-14})} =$$
$$= 8,38 \text{ MHz}$$

Output pole

$$f_{p,out} = \frac{1}{2\pi R_D // r_o (C_{GD} + C_{BD})} =$$
$$= \frac{1}{2\pi (528 // 4049) (2 \cdot 10^{-14} + 2,73 \cdot 10^{-14})} =$$
$$= 7,2 \text{ GHz} \quad f_{p,out} \gg f_{p,in}$$



Dominating pole at 8,38 MHz from approximate analysis with poles associated to nodes.

Dominating pole at 8.42 MHz from simulation.